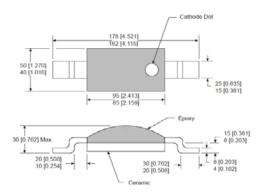
# **MBD1047-E28X Planar Tunnel Diode**

# E28X Non-Hermetic



# **Technical Characteristics**

# **Product Features**

Rugged Germanium Planar Construction

**Excellent Temperature Stability** 

No DC Bias Required

Wide Video Bandwidth

MIL-STD-190500 & 883 Qualified

# **Product Description**

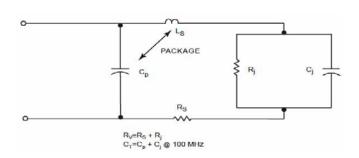
EclipseMDI MBD1047-E28X, is a zero-bias, rugged Planar Tunnel Diode constructed with Germanium Planar. This tunnel diode exhibits excellent temperature stability, wide video bandwidth and is MIL STD-190500 & MIL-STD-883C qualified. The MBD1047 is also available in hermetic (E28) ceramic packages.

# **Maximum Ratings**

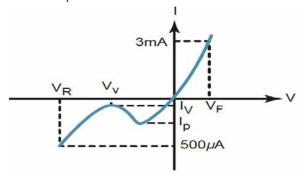
Storage Temperature	65° to +125°C
Operating Temperature	65° to +110°C
Input Power Handling	+17dBm CW
or 3 ERG spike	
Soldering Temperature	+160° C

	Specifications Specification				
Parameters	Conditions	MIN	Typical	MAX	UNITS
lp		100		150	μΑ
Cj	Vr=Vv, f=100MHz			.30	pF
K[Y]	Pin=-20dBm		1000		mV/mW
Rv	R)Load)=10K, f=10GHz		180		Ω Ohms
lp/lv		2.5			
Vr	If=500μA		420		mV
Vf	If=3mA			135	mV

#### Diode equivalent circuit



# Back diode parameters



# About EclipseMDI

ECLIPSE Microdevices is located in San Jose, California. ECLIPSE has been developing high performance analog semiconductors for use in wireless radio frequency (RF), microwave, and millimeter wave for commercial and industrial applications. ECLIPSE has formed a strategic alliances - with foundries that features leading state-of-the-art process technologies and with manufacturing facilities for high-volume production of innovative RFIC's.

# **Product Export Classificiation**

ECCN: EAR 99 (unless otherwise specified) HTS: 8542330000





